

Features

- Trench LV MOSFET Technology
- Moisture Sensitivity Level 3
- Halogen Free. "Green" Device^(Note1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

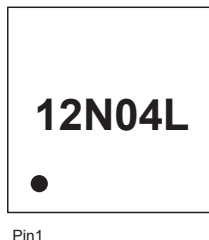
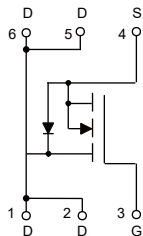
- Operating Junction Temperature Range: -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 70°C/W Junction to Ambient^(Note2)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V _{DS}	40	V
Gate-Source Voltage	V _{GS}	±20	V
Continuous Drain Current	I _D	T _A =25°C	12
		T _A =100°C	7.5
Pulsed Drain Current ^(Note 3)	I _{DM}	48	A
Total Power Dissipation ^(Note 4)	P _D	1.8	W

Note:

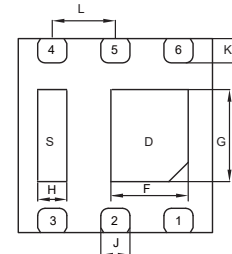
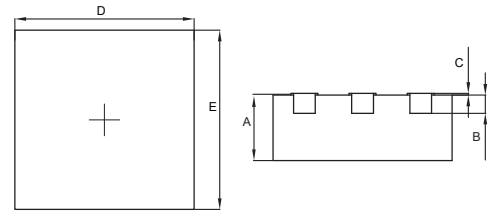
1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
2. The value of R_{θJA} is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with T_A =25°C.
3. Repetitive rating; pulse width limited by max. junction temperature.
4. P_D is based on max. junction temperature, using junction-ambient thermal resistance.

Internal Structure and Marking Code



N-CHANNEL MOSFET

DFN2020-6LE



DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.030	0.033	0.750	0.850	
B	0.008		0.200		REF.
C	0.000	0.002	0.000	0.050	
D	0.075	0.083	1.900	2.100	
E	0.075	0.083	1.900	2.100	
F	0.024	0.031	0.610	0.810	
G	0.028	0.036	0.710	0.910	
H	0.008	0.016	0.200	0.400	
J	0.010	0.014	0.250	0.350	
K	0.008	0.012	0.200	0.300	
L	0.026		0.650		TYP.

N-Channel MOSFET Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=250\mu A$	40			V
Gate-Source Leakage Current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 20V$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=40V, V_{GS}=0V$			1	μA
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1	1.5	2.5	V
Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=9A$		9.3	12	m Ω
		$V_{GS}=4.5V, I_D=5A$		13	16	
Gate Resistance	R_g	f=1MHz, Open drain		2.5		Ω
Diode Characteristics						
Continuous Body Diode Current	I_S				12	A
Diode Forward Voltage	V_{SD}	$V_{GS}=0V, I_S=9A$			1.2	V
Reverse Recovery Time	t_{rr}	$I_S=20A, di_F/dt=300A/\mu s$		12.5		ns
Reverse Recovery Charge	Q_{rr}			10		nC
Dynamic Characteristics						
Input Capacitance	C_{iss}	$V_{DS}=25V, V_{GS}=0V, f=1MHz$		990		pF
Output Capacitance	C_{oss}			96		
Reverse Transfer Capacitance	C_{rss}			84		
Total Gate Charge	Q_g	$V_{DS}=20V, V_{GS}=10V, I_D=20A$		23		nC
Gate-Source Charge	Q_{gs}			3.5		
Gate-Drain Charge	Q_{gd}			6		
Turn-On Delay Time	$t_{d(on)}$	$V_{GS}=10V, V_{DD}=20V, I_D=20A$		3.8		ns
Turn-On Rise Time	t_r			58		
Turn-Off Delay Time	$t_{d(off)}$			20		
Turn-Off Fall Time	t_f			2.5		

Curve Characteristics

Fig. 1 - Typical Output Characteristics

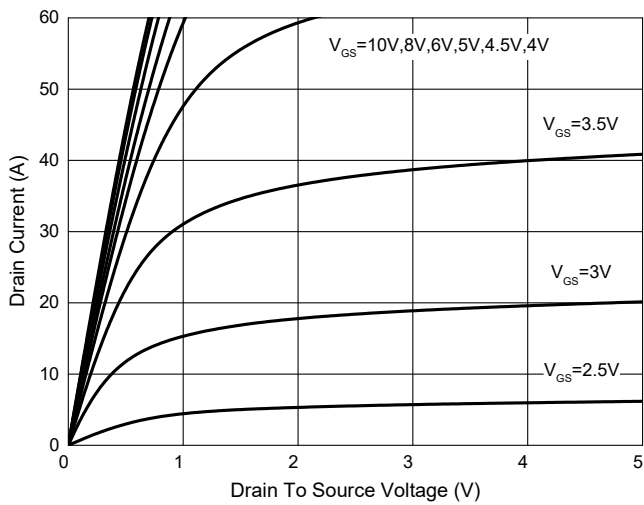


Fig. 2 - Transfer Characteristics

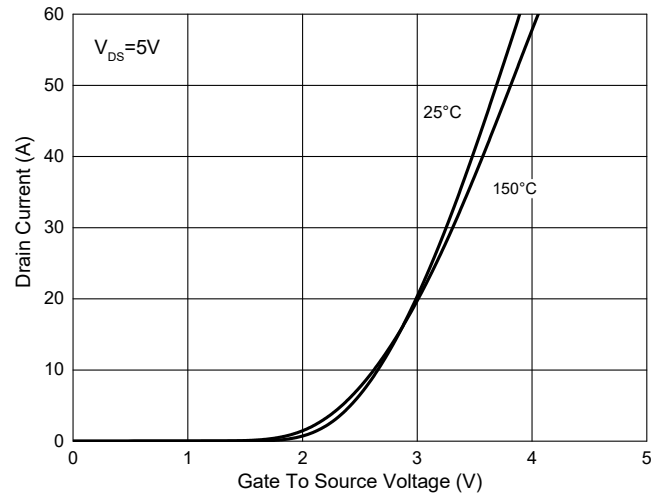


Fig. 3 - $R_{DS(ON)} - V_{GS}$

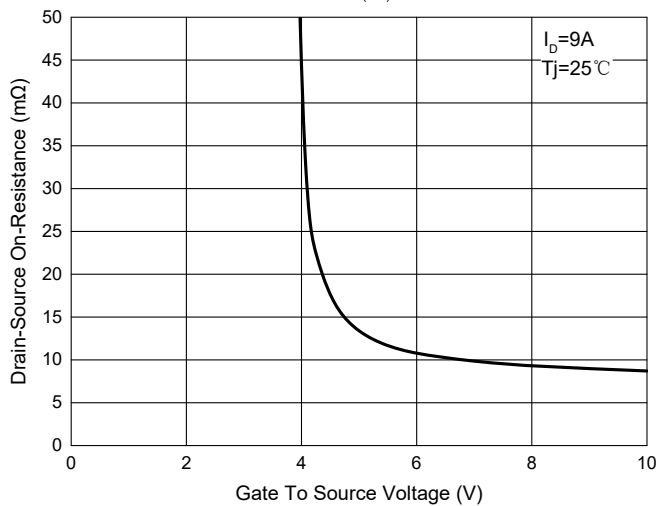


Fig. 4 - $R_{DS(ON)} - I_D$

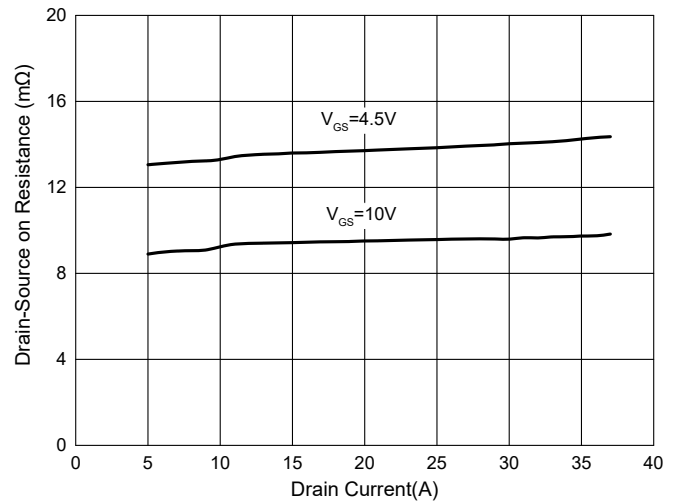


Fig. 5 - Capacitance Characteristics

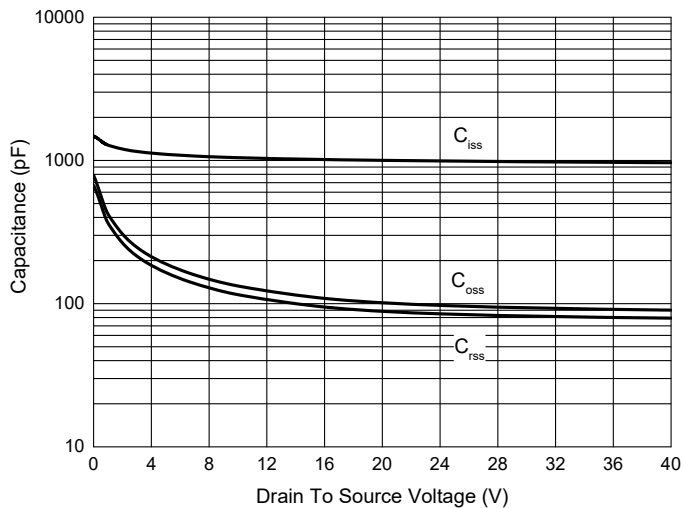
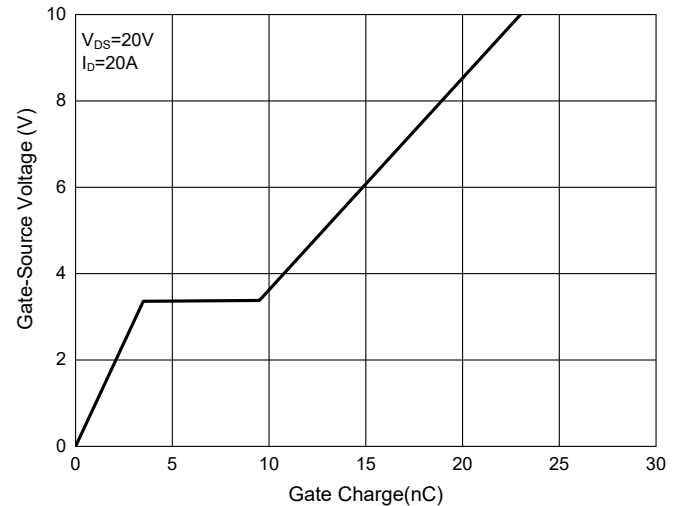


Fig. 6 - Gate Charge



Curve Characteristics

Fig. 7 - Normalized Threshold Voltage

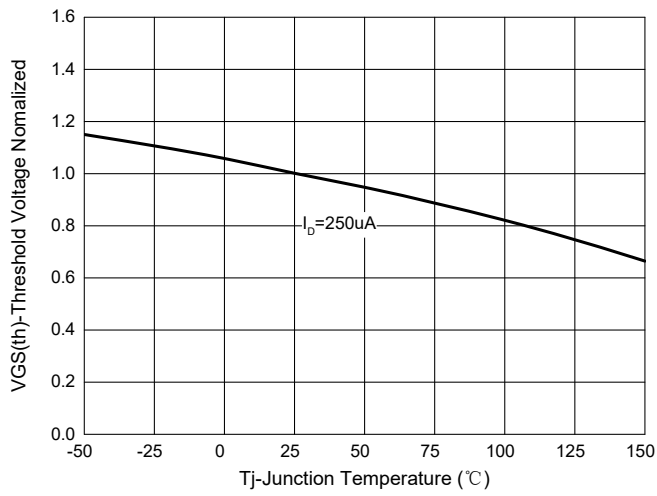


Fig. 8 - Normalized On Resistance Characteristics

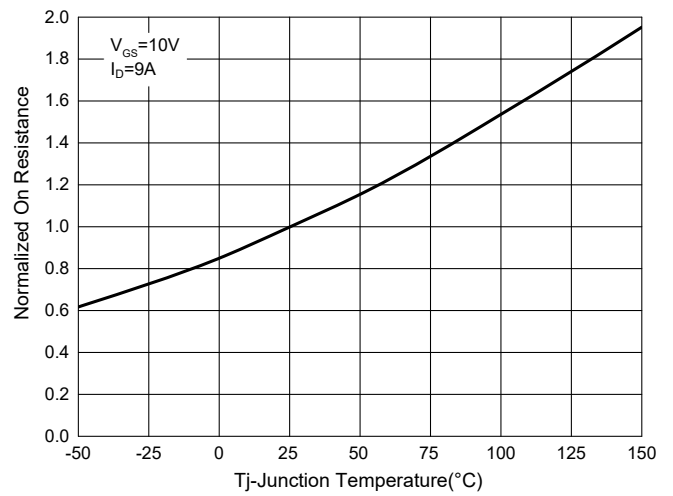


Fig. 9 - $I_S - V_{SD}$

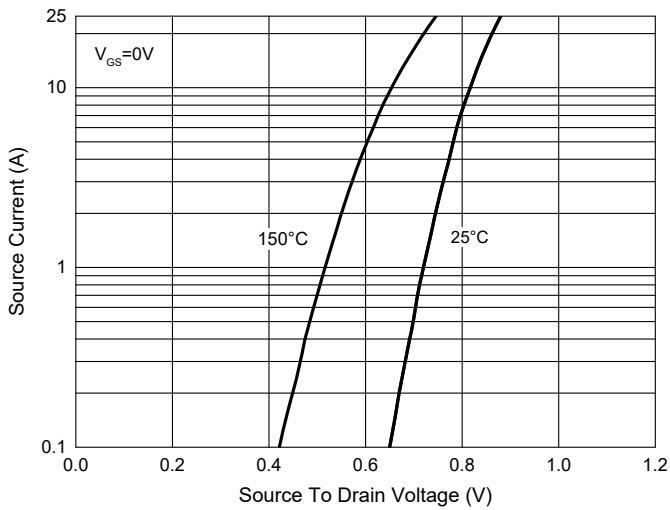


Fig. 10 - Current dissipation

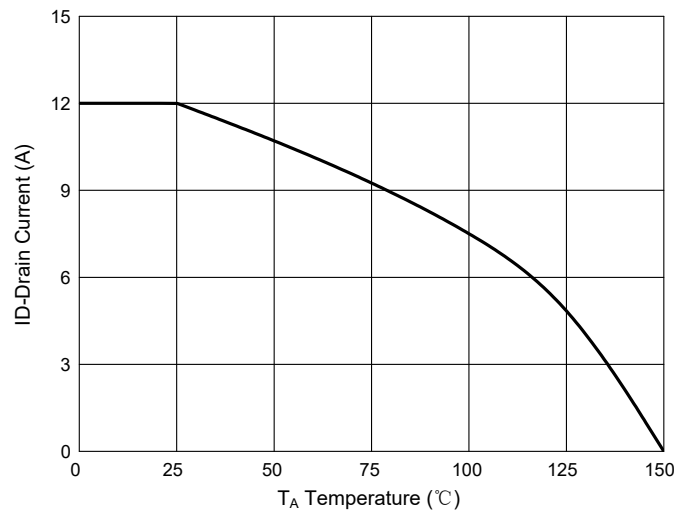
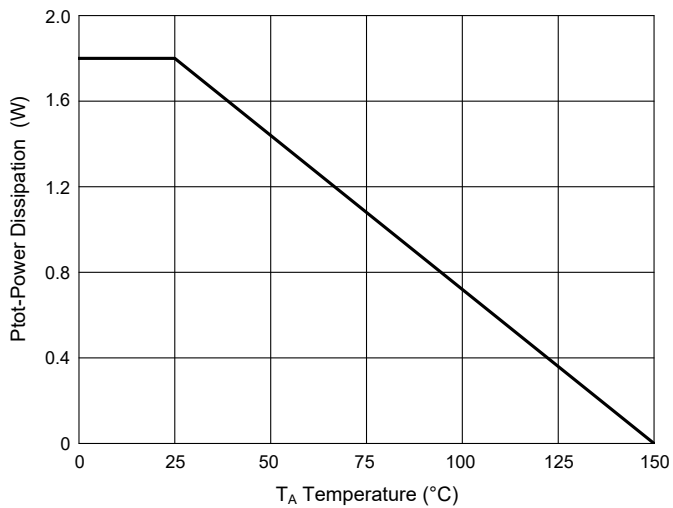


Fig. 11 - PD—TJ



Curve Characteristics

Fig. 12 - Safe Operation Area

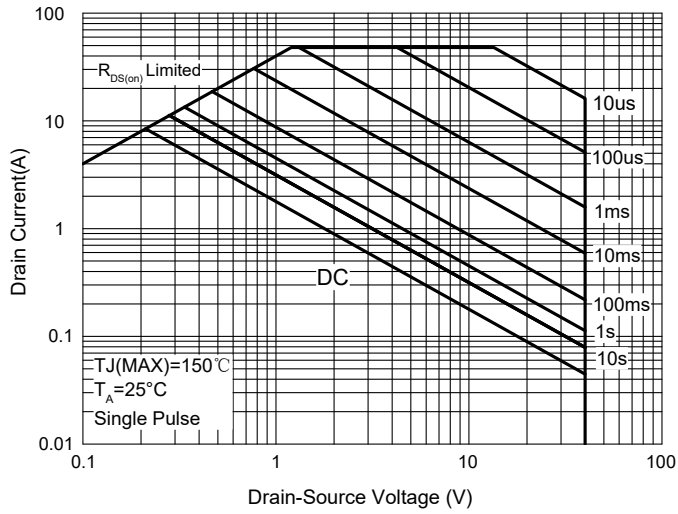
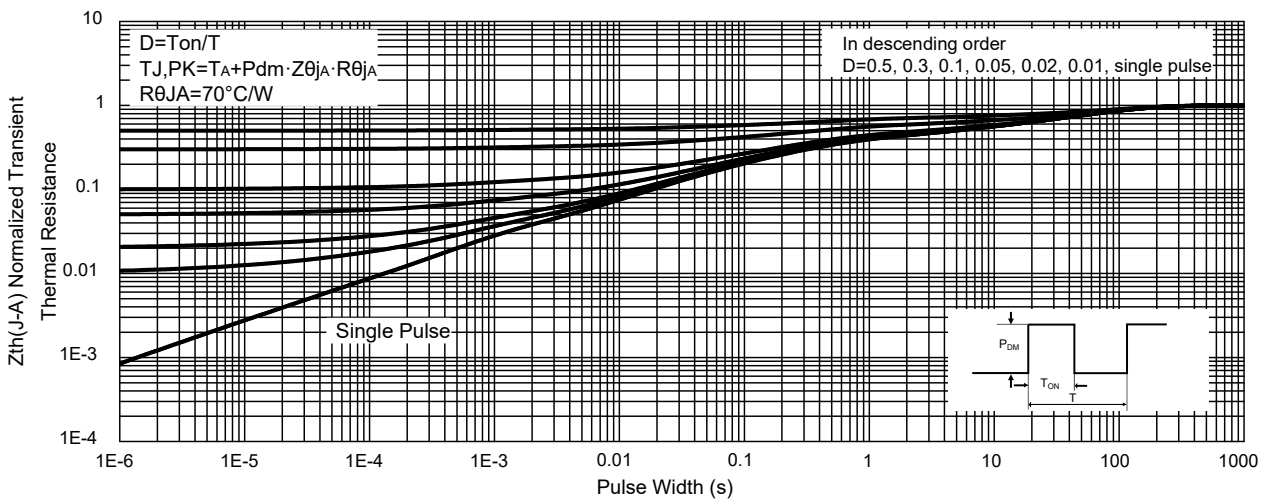


Fig. 13 - Normalized Transient Thermal Impedance



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel:3Kpcs/Reel

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